

LOW POWER DUAL OPERATIONAL AMPLIFIERS SA/SE/NE532/LM158/258/358

DESCRIPTION

The 532/358 consists of two independent, high gain, internally frequency compensated operational amplifiers designed specifically to operate from a single power supply over a wide range of voltages. Operation from dual power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

FEATURES

- Internally frequency compensated for unity gain
- Large dc voltage gain—(100dB)
- Wide bandwidth (unity gain)—1MHz (temperature compensated)
- Wide power supply range
single supply—(3Vdc to 30Vdc)
or dual supplies—(± 1.5 Vdc to ± 15 Vdc)
- Very low supply current drain (400 μ A)—essentially independent of supply voltage (1mW/op amp at +5Vdc)
- Low input biasing current—(45nA dc temperature compensated)
- Low input offset voltage—(2mVdc) and offset current—(5nA dc)

- Differential input voltage range equal to the power supply voltage
- Large output voltage—(0Vdc to $V^+ - 1.5$ Vdc swing)
- SE532 MIL-STD-883A,B,C available

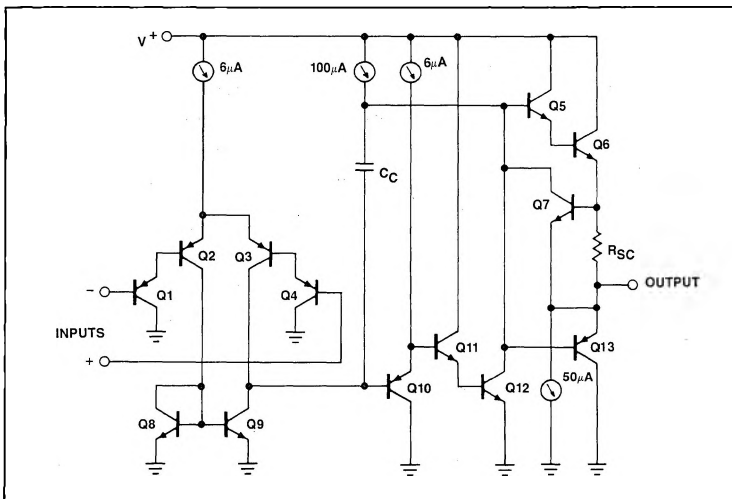
UNIQUE FEATURES

In the linear mode the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage. The unity gain cross frequency is temperature compensated. The input bias current is also temperature compensated.

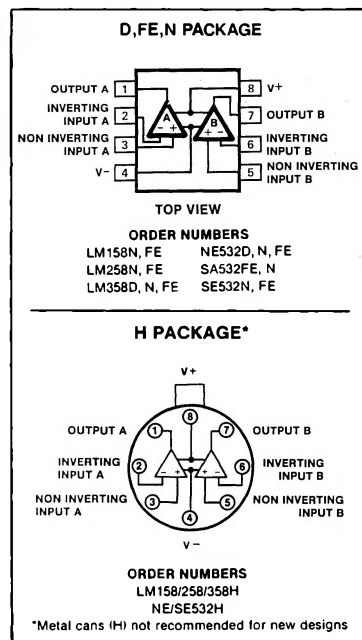
ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING	UNIT
Supply voltage, V^+	32 or ± 16	Vdc
Differential input voltage	32	Vdc
Input voltage	-0.3 to +32	Vdc
Power dissipation ¹		
FE package	900	mW
H package	680	mW
N package	500	mW
Output short-circuit to GND ⁵ $V^+ < 15$ Vdc and $T_A = 25^\circ\text{C}$	Continuous	
Operating temperature range		
NE532/LM358	0 to +70	$^\circ\text{C}$
LM258	-25 to +85	$^\circ\text{C}$
SA532N	-40 to +85	$^\circ\text{C}$
SE532/LM158	-55 to +125	$^\circ\text{C}$
Storage temperature range	-65 to +150	$^\circ\text{C}$
Lead temperature (soldering, 10sec)	300	$^\circ\text{C}$

EQUIVALENT CIRCUIT



PIN CONFIGURATIONS



LOW POWER DUAL OPERATIONAL AMPLIFIERS SA/SE/NE532/LM158/258/358

DC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_+ = +5\text{V}$ unless otherwise specified.

PARAMETER	TEST CONDITIONS	SE532, LM158/258			NE/SA532/LM358			UNIT
		Min	Typ	Max	Min	Typ	Max	
V_{OS} Offset voltage ¹	$R_S \leq 0\Omega$ $R_S \leq 0\Omega$, over temp.		± 2	± 5 ± 7		± 2	± 7 ± 9	mV mV
V_{OS} Drift	$R_S = 0\Omega$, over temp.		7			7		$\mu\text{V}/^\circ\text{C}$
I_{OS} Offset current	$I_{IN}(+) - I_{IN}(-)$ Over temp.		± 3	± 30 ± 100		± 5	± 50 ± 150	nA nA
I_{OS} Drift	Over temp.		10			10		$\mu\text{A}/^\circ\text{C}$
I_{BIAS} Input current ²	$I_{IN}(+)$ or $I_{IN}(-)$ Over temp., $I_{IN}(+)$ or $I_{IN}(-)$		45 40	150 300		45 40	250 500	nA nA
I_B Drift	Over temp		50			50		$\mu\text{A}/^\circ\text{C}$
V_{CM} Common mode voltage range ³	$V_+ = 30\text{V}$ Over temp., $V_+ = 30\text{V}$	0 0		$V_+ - 1.5$ $V_+ - 2.0$	0 0		$V_+ - 1.5$ $V_+ - 2.0$	V V
C_{MRR} Common mode rejection ratio	$V_+ = 30\text{V}$	70	85		65	70		dB
V_{OUT} Output voltage swing (V_{OH})	$R_L \geq 2k\Omega$, $V_+ = 30\text{V}$, over temp. $R_L \geq 10k\Omega$, $V_+ = 30\text{V}$, over temp.	26 27	28		26 27	28		V V
V_{OUT} Output voltage swing (V_{OL})	$R_L \leq 10k\Omega$, over temp.		5	20		5	20	mV
I_{CC} Supply current	$R_L = \infty$, $V_+ = 30\text{V}$ $R_L = \infty$ on all amplifiers, over temp.		1.0 0.5	2.0 1.2		1.0 0.5	2.0 1.2	mA mA
A_{VOL} Large signal voltage gain	$R_L \geq 2k\Omega$, $V_{OUT} \pm 10\text{V}$, $V_+ = 15\text{V}$ (for large V_O swing) over temp.	50 25	100		25 15	100		V/mV V/mV
PSRR Supply voltage rejection ratio	$R_S \leq 0\Omega$	65	100		65	100		dB
Amplifier-to-amplifier coupling ⁴	$f = 1\text{kHz}$ to 20kHz (input referred)		-120			-120		dB
Output current Source Sink	$V_{IN+} = +1\text{Vdc}$, $V_{IN-} = 0\text{Vdc}$, $V_+ = 15\text{Vdc}$	20	40		20	40		mA
	$V_{IN+} = +1\text{Vdc}$, $V_{IN-} = 0\text{Vdc}$, $V_+ = 15\text{Vdc}$, over temp.	10	20		10	20		mA
	$V_{IN-} = +1\text{Vdc}$, $V_{IN+} = 0\text{Vdc}$, $V_+ = 15\text{Vdc}$	10	20		10	20		mA
	$V_{IN-} = +1\text{Vdc}$, $V_{IN+} = 0\text{Vdc}$, $V_+ = 15\text{Vdc}$, over temp.	5	8		5	8		mA
	$V_{IN+} = 0\text{V}$, $V_{IN-} = +1\text{Vdc}$, $V_O = 200\text{mV}$	12	50		12	50		μA
I_{SC} Short circuit current ⁵			40	60		40	60	mA
Differential input voltage ⁶				V_+			V_+	V
GBW Unity gain bandwidth	$T_A = 25^\circ\text{C}$		1			1		MHz
S.R. Slew rate	$T_A = 25^\circ\text{C}$		0.3			0.3		$\text{V}/\mu\text{s}$
Noise Input Noise Voltage	$T_A = 25^\circ\text{C}$, $f = 1\text{kHz}$		40			40		$\text{nV}/\sqrt{\text{Hz}}$

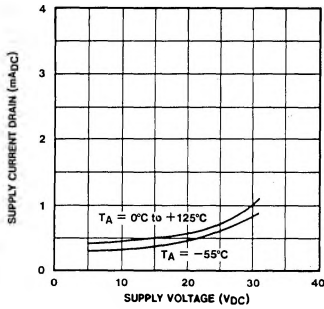
NOTES

- $V_O \approx 1.4\text{V}$, $R_S = 0\Omega$ with V_+ from 5V to 30V; and over the full input common-mode range (0V to $V_+ - 1.5\text{V}$).
- The direction of the input current is out of the IC due to the pnp input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.
- The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is $V_+ - 1.5\text{V}$, but either or both inputs can go to $+32\text{V}$ without damage.
- Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance coupling increases at higher frequencies.
- Short circuits from the output to V_+ can cause excessive heating and eventual destruction. The maximum output current is approximately 40mA independent of the magnitude of V_+ . At values of supply voltage in excess of $+15\text{Vdc}$, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.
- The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is $V_+ - 1.5\text{V}$, but either or both inputs can go to $+32\text{Vdc}$ without damage.
- For operating at high temperatures, all devices must be derated based on a $+125^\circ\text{C}$ maximum junction temperature and a thermal resistance of $175^\circ\text{C}/\text{W}$ which applies for the device soldered in a printed circuit board, operating in a still air ambient.

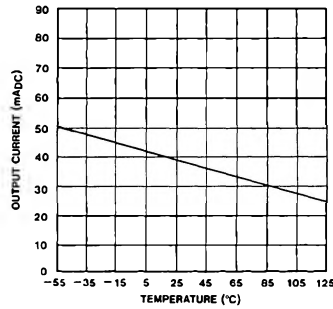
LOW POWER DUAL OPERATIONAL AMPLIFIERS SA/SE/NE532/LM158/258/358

TYPICAL PERFORMANCE CHARACTERISTICS

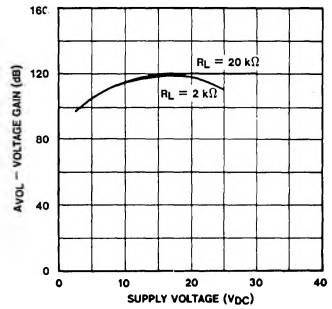
SUPPLY CURRENT



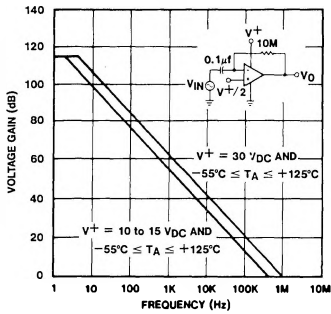
CURRENT LIMITING



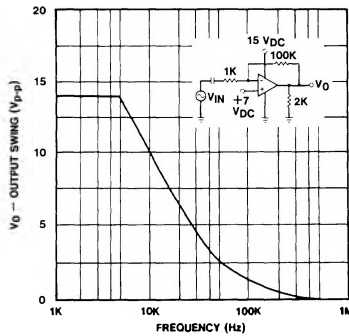
VOLTAGE GAIN



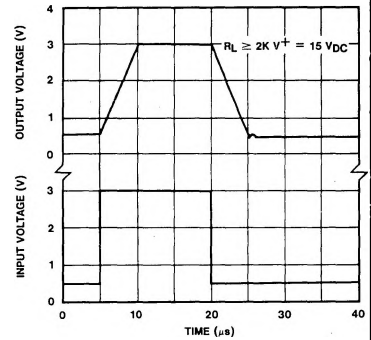
OPEN LOOP FREQUENCY RESPONSE



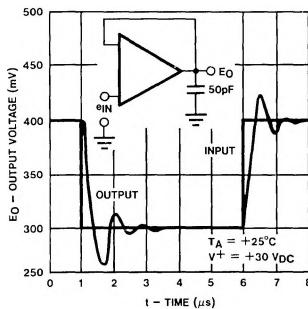
LARGE SIGNAL FREQUENCY RESPONSE



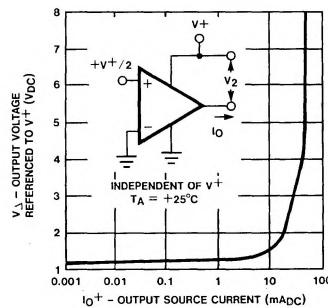
VOLTAGE FOLLOWER PULSE RESPONSE



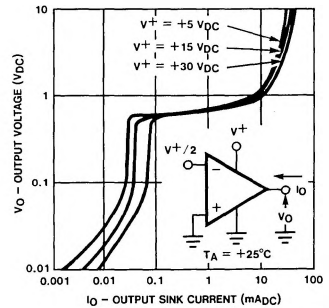
VOLTAGE FOLLOWER PULSE RESPONSE (SMALL SIGNAL)



OUTPUT CHARACTERISTICS CURRENT SOURCING

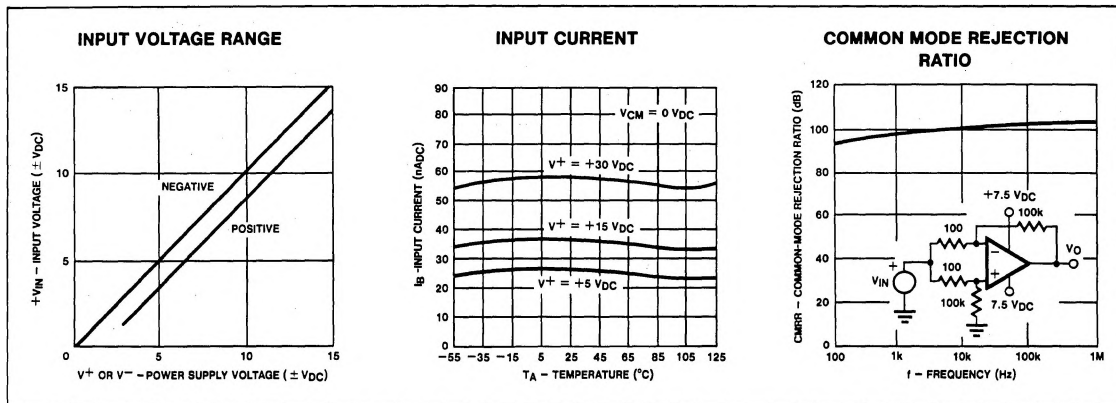


OUTPUT CHARACTERISTICS CURRENT SINKING

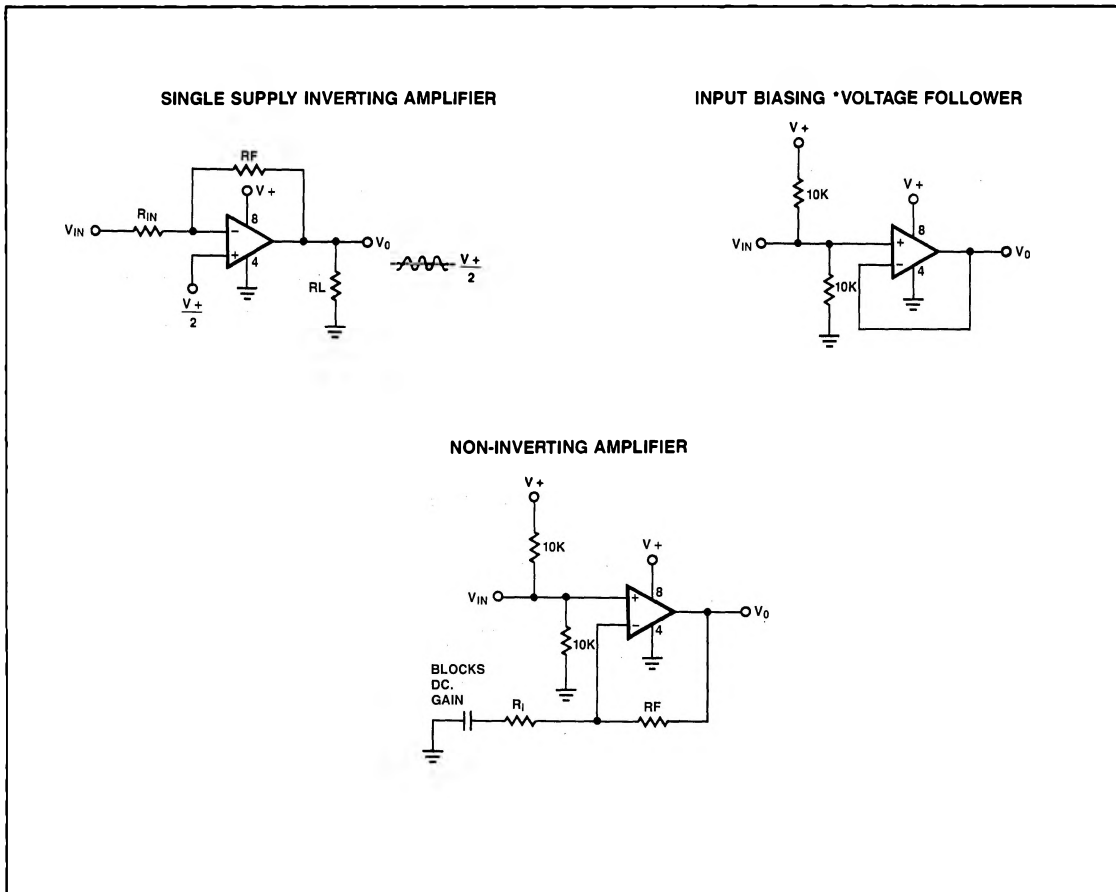


LOW POWER DUAL OPERATIONAL AMPLIFIERS SA/SE/NE532/LM158/258/358

TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)



TYPICAL APPLICATIONS



GENERAL PURPOSE OPERATIONAL AMPLIFIER

MC/SA1458/MC1558

DESCRIPTION

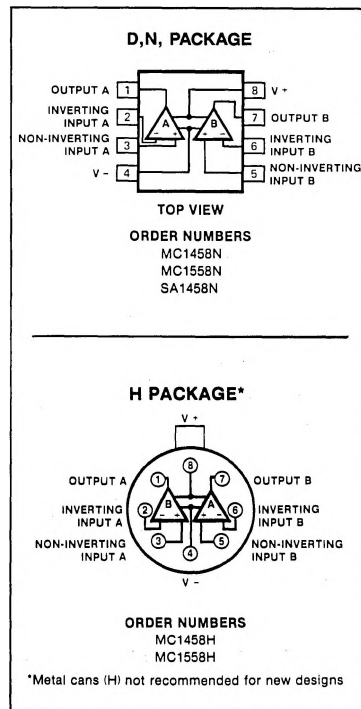
The MC1458 is a high performance operational amplifier with high open loop gain, internal compensation, high common mode range and exceptional temperature stability. The MC1458 is short-circuit protected and allows for nulling of offset voltage.

The MC1458/SA1458/MC1558 consists of a pair of 741 operational amplifiers on a single chip.

FEATURES

- Internal frequency compensation
- Short circuit protection
- Excellent temperature stability
- High input voltage range
- No latch-up
- 1558/1458 are 2 "op amps" in space of one 741 package
- MC1558 MIL-STD-883A,B,C available

PIN CONFIGURATIONS



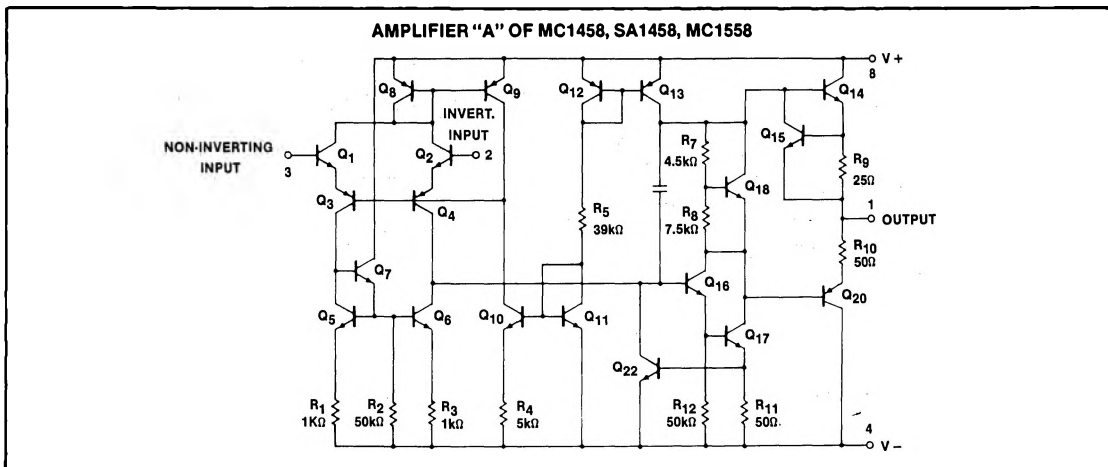
ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING	UNIT
Supply voltage		
MC1458	± 18	V
SA1458	± 18	V
MC1558	± 22	V
Internal power dissipation		
N package	500	mW
H package ¹	800	mW
F,FE package	1000	mW
Differential input voltage	± 30	V
Input voltage ²	± 15	V
Output short-circuit duration	Continuous	
Operating temperature range		$^{\circ}\text{C}$
MC1458	0 to +70	
SA1458	-40 to +85	
MC1558	-55 to +125	
Storage temperature range	-65 to +150	$^{\circ}\text{C}$
Lead temperature (soldering 60sec)	300	$^{\circ}\text{C}$

NOTES

1. Ratings based on thermal resistances, junction to ambient, of 240 $^{\circ}\text{C/W}$, 150 $^{\circ}\text{C/W}$, 110 $^{\circ}\text{C/W}$ for N, H, F and FE packages respectively, and a maximum junction temperature of 150 $^{\circ}\text{C}$.
2. For supply voltages less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

EQUIVALENT SCHEMATIC



GENERAL PURPOSE OPERATIONAL AMPLIFIER

MC/SA1458/MC1558

DC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise specified.

PARAMETER	TEST CONDITIONS	MC1558			UNIT
		Min	Typ	Max	
V_{OS} Offset voltage	$R_S = 10\text{k}\Omega$		1.0	5.0	mV
ΔV_{OS} Offset voltage	$R_S = 10\text{k}\Omega$, over temperature Over temperature		10	6.0	mV $\mu\text{V}/^\circ\text{C}$
I_{OS} Offset current	Over temperature		20	200	nA
ΔI_{OS} Offset current	Over temperature		0.10	500	nA $\text{nA}/^\circ\text{C}$
I_{BIAS} Input bias current	Over temperature		80	500	nA
ΔI_B Bias current	Over temperature		1.0	1500	nA $\text{nA}/^\circ\text{C}$
V_{OUT} Output voltage swing	$R_L = 10\text{k}\Omega$, over temperature $R_L = 2\text{k}\Omega$, over temperature	± 12 ± 10	± 14 ± 13		V V
A_{VOL} Large signal voltage gain	$R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$ $R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$, over temperature	50 20	100		V/mV V/mV
Offset voltage adjustment range			± 30		mV
PSRR Supply voltage rejection ratio	$R_S \leq 10\text{k}\Omega$		30	150	$\mu\text{V}/\text{V}$
CMRR Common mode rejection ratio		70	90		dB
I_{CC} Supply current			2.3	5.0	mA
V_{IN} Input voltage range		± 12	± 13		V
P_d Power consumption			70	150	mW
R_{OUT} Channel separation			120		dB
I_{SC} Output resistance			75		Ω
		10	26	60	mA

DC ELECTRICAL CHARACTERISTICS (Cont'd) $T_A = 25^\circ\text{C}$, $V_{CC} = \pm 15\text{V}$, unless otherwise specified.¹

PARAMETER	TEST CONDITIONS	MC1458			SA1458			UNIT
		Min	Typ	Max	Min	Typ	Max	
V_{OS} Offset voltage	$R_S = 10\text{k}\Omega$		2.0	6.0		2.0	6.0	mV
ΔV_{OS} Offset voltage	$R_S = 10\text{k}\Omega$, over temp. Over temperature		12	7.5		12	7.5	mV $\mu\text{V}/^\circ\text{C}$
I_{OS} Offset current	Over temperature		20	200		20	200	nA
ΔI_{OS} Offset current	Over temperature		0.10	300		0.10	500	nA $\text{nA}/^\circ\text{C}$
I_{BIAS} Input bias current	Over temperature		80	500		80	500	nA
ΔI_B Bias current	Over temperature		1.0	800		1.0	1500	nA $\text{nA}/^\circ\text{C}$
V_{OUT} Output voltage swing	$R_L = 10\text{k}\Omega$ $R_L = 2\text{k}\Omega$, over temp.	± 12 ± 10	± 14 ± 13		± 12 ± 10	± 14 ± 13		V V
A_{VOL} Large signal voltage gain	$R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$ $R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$, Over temperature	25 15	200		20 15	200		V/mV V/mV
Offset voltage adjustment range			± 30			± 30		mV
PSRR Supply voltage rejection ratio	$R_S \leq 10\text{k}\Omega$		30	150		30	150	$\mu\text{V}/\text{V}$
CMRR Common mode rejection ratio		70	90		70	90		dB
I_{CC} Supply current			2.3	5.6		2.3	5.6	mA
V_{IN} Input voltage range		± 12	± 13		± 12	± 13		V
R_{IN} Input resistance								M Ω
P_d Power consumption			70	170		70	170	mW
Channel separation			120			120		dB
I_{SC} Output short-circuit current			25			25		mA

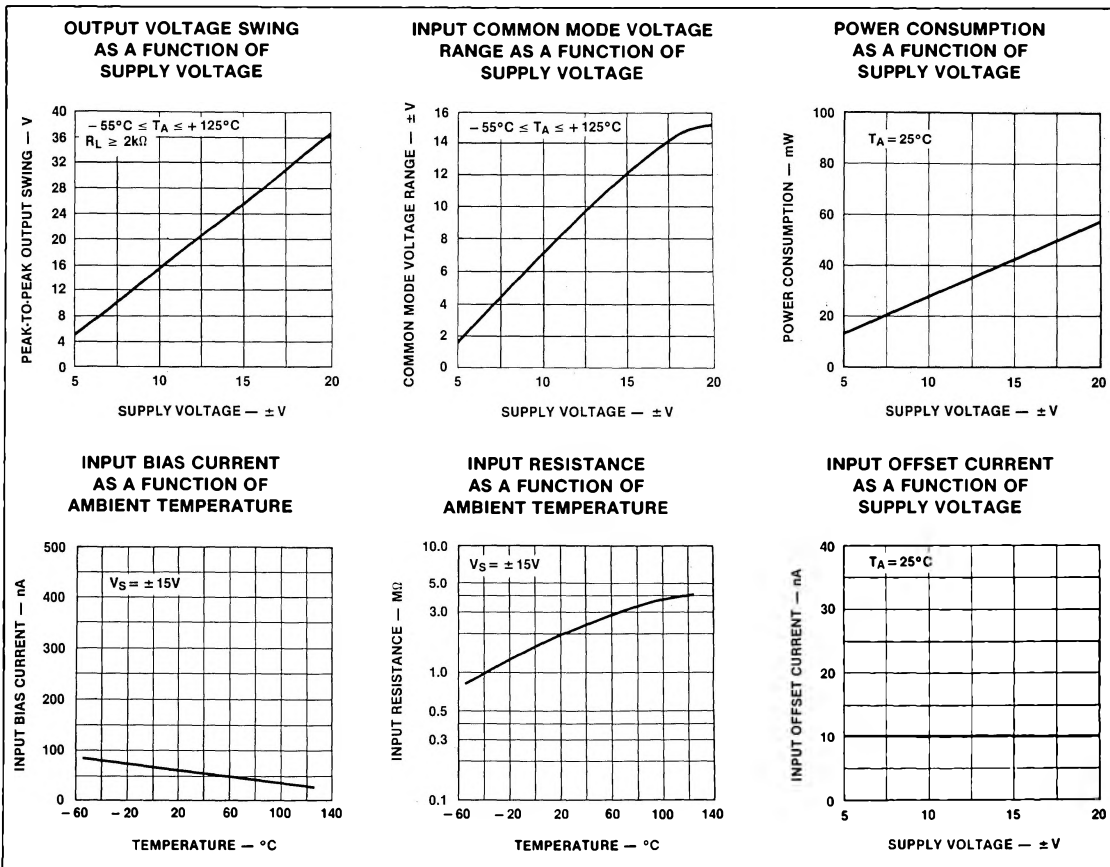
GENERAL PURPOSE OPERATIONAL AMPLIFIER

MC/SA1458/MC1558

AC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise specified.

PARAMETER	TEST CONDITIONS	MC1458, SA1458, MC1558			UNIT
		Min	Typ	Max	
Parallel input resistance	Open loop, $f = 20\text{Hz}$	0.3			$\text{M}\Omega$
Common mode input impedance	$f = 20\text{Hz}$		200		$\text{M}\Omega$
Equivalent input noise voltage	$A_V = 100$, $R_S = 10\text{k}\Omega$, $B_W = 1.0\text{kHz}$, $f = 1.0\text{kHz}$		30		$\text{nV}/\sqrt{\text{Hz}}$
Power bandwidth	$A_V = 1$, $R_L = 2.0\text{k}\Omega$, $\text{THD} \leq 5\%$, $V_{\text{OUT}} = 20\text{Vp-p}$		14		kHz
Phase margin			65		degrees
Gain margin			11		dB
Unity gain crossover frequency	Open loop		1.0		MHz
Transient response unity gain	$V_{\text{IN}} = 20\text{mV}$, $R_L = 2\text{k}\Omega$, $C_L \leq 100\text{pF}$		0.3		μs
Rise time			5.0		%
Overshoot			0.8		$\text{V}/\mu\text{s}$
Slew rate	$C \leq 100\text{pF}$, $R_L \geq 2\text{k}$, $V_{\text{IN}} = \pm 10\text{V}$				

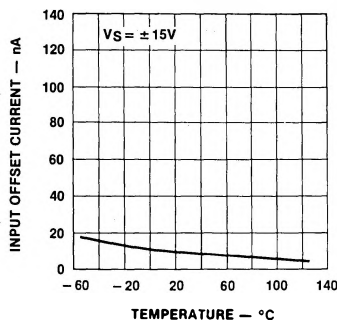
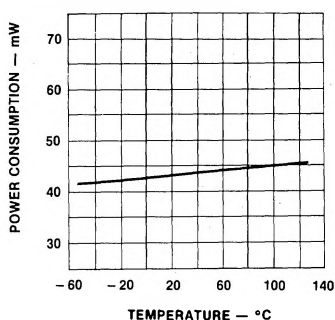
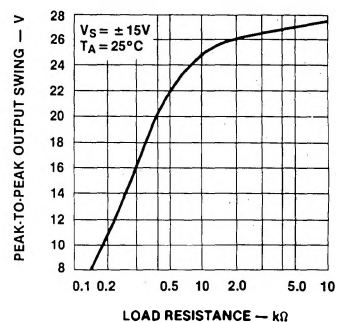
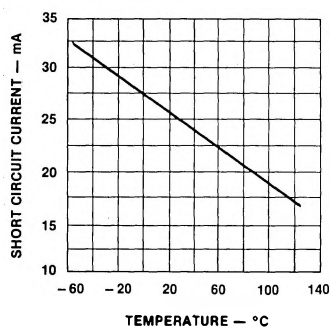
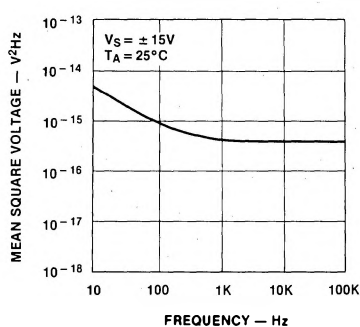
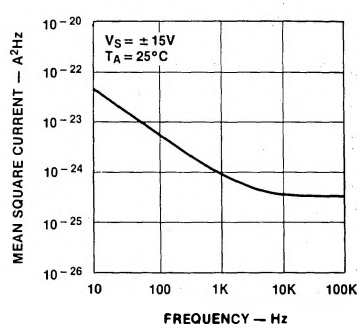
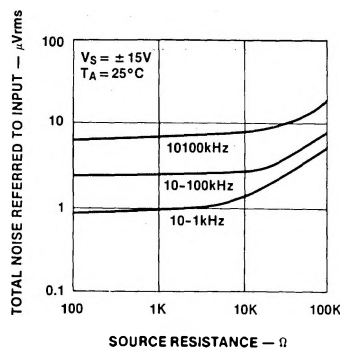
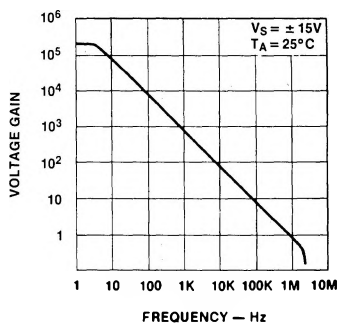
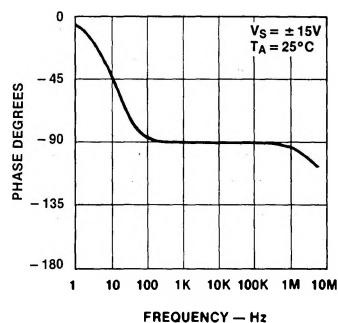
TYPICAL PERFORMANCE CHARACTERISTICS



GENERAL PURPOSE OPERATIONAL AMPLIFIER

MC/SA1458/MC1558

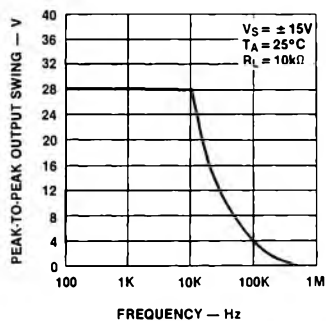
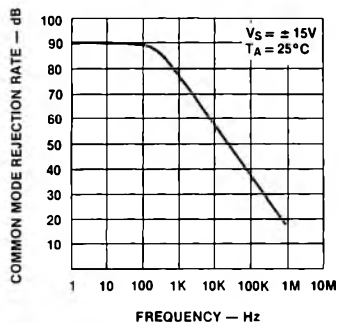
TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)

INPUT OFFSET CURRENT
AS A FUNCTION OF
AMBIENT TEMPERATUREPOWER CONSUMPTION
AS A FUNCTION OF
AMBIENT TEMPERATUREOUTPUT VOLTAGE SWING
AS A FUNCTION OF
LOAD RESISTANCEOUTPUT SHORT-CIRCUIT CURRENT
AS A FUNCTION OF
AMBIENT TEMPERATUREINPUT NOISE VOLTAGE
AS A FUNCTION OF
FREQUENCYINPUT NOISE CURRENT
AS A FUNCTION OF
FREQUENCYBROADBAND NOISE FOR
VARIOUS BANDWIDTHSOPEN LOOP VOLTAGE GAIN
AS A FUNCTION OF
FREQUENCYOPEN LOOP PHASE RESPONSE
AS A FUNCTION OF
FREQUENCY

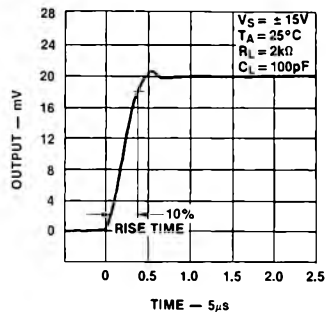
GENERAL PURPOSE OPERATIONAL AMPLIFIER

MC/SA1458/MC1558

TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)

OUTPUT VOLTAGE SWING
AS A FUNCTION OF
FREQUENCYCOMMON MODE REJECTION
RATIO AS A FUNCTION OF
FREQUENCY

TRANSIENT RESPONSE

POWER BANDWIDTH
(Large Signal Swing vs Frequency)